TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX245F,TC74LCX245FW,TC74LCX245FT,TC74LCX245FK

Low-Voltage Octal Bus Transceiver with 5-V Tolerant Inputs and Outputs

The TC74LCX245F/FW/FT/FK is a high-performance CMOS octal bus transceiver. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

The direction of data transmission is determined by the level of the DIR input. The enable input ($\overline{\text{OE}}$) can be used to disable the device so that the busses are effectively isolated.

All inputs are equipped with protection circuits against static discharge.

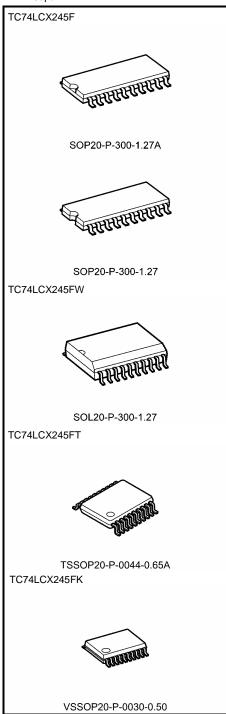
Features (Note)

- Low-voltage operation: VCC = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 7.0 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Ouput current: | IOH | /IOL = 24 mA (min) (VCC = 3.0 V)
- Latch-up performance: ±500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- Bidirectional interface between 5.0 V and 3.3 V signals
- · Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 245 type

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

All floating (high impedance) bus pins must have their input levels fixed by means of pull-up or pull-down resistors.

Note: xxxFW (JEDEC SOP) is not available in Japan.



Weight

 SOP20-P-300-1.27A
 : 0.22g (typ.)

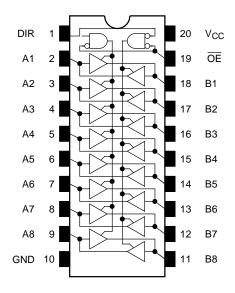
 SOP20-P-300-1.27
 : 0.22g (typ.)

 SOL20-P-300-1.27
 : 0.46 g (typ.)

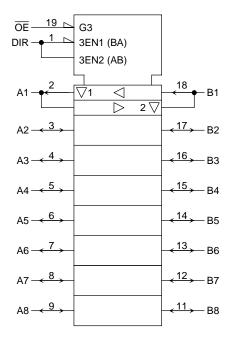
 TSSOP20-P-0044-0.65A
 : 0.08 g (typ.)

 VSSOP20-P-0030-0.50
 : 0.03 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inputs		Outputs	Function		
ŌE	DIR	Odipuis	A-Bus	B-Bus	
L	L	A = B	Output	Input	
L	Н	B = A	Input	Output	
Н	Х	Z	Z	7	

X: Don't care

Z: High impedance

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Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	−0.5 to 7.0	V
DC input voltage (DIR, $\overline{\text{OE}}$)	V _{IN}	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC bus I/O voltage	V _{I/O}	-0.5 to V _{CC} + 0.5	V
		(Note 3)	
Input diode current	I _{IK}	-50	mA
Output diode current	I _{OK}	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	P _D	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Recommended Operating Conditions (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	Vcc	2.0 to 3.6		
r ower supply voltage	v CC	1.5 to 3.6 (Note 2)	V	
Input voltage (DIR, $\overline{\text{OE}}$)	V _{IN}	0 to 5.5	V	
Bus I/O voltage	V _{I/O}	0 to 5.5 (Note 3)	V	
Bus I/O voltage	V I/O	0 to V _{CC} (Note 4)		
Output current	I _{OH} /I _{OI}	±24 (Note 5)	mA	
Output current	iOH/iOL	±12 (Note 6)	IIIA	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V	

Note 1: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

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Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 6: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V



Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics		Symbol	Test Condition			Min	Max	Unit
		,					Max	
Input voltage	H-level	V_{IH}		_	2.7 to 3.6	2.0	_	V
input voltage	L-level	V _{IL}		_	2.7 to 3.6		0.8	V
				$I_{OH} = -100 \mu A$	2.7 to 3.6	V _{CC} - 0.2	_	
	H-level	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	V
			$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 100 μA	2.7 to 3.6	_	0.2	
	L-level			I _{OL} = 12 mA	2.7	_	0.4	
	L-ievei	L-level V _{OL}		I _{OL} = 16 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage currer	nt	I _{IN}	$V_{IN} = 0 \text{ to } 5.5 \text{ V}$		2.7 to 3.6	_	±5.0	μА
3-state output OFF state current		1	$V_{IN} = V_{IH}$ or V_{IL}		2.7 to 3.6		.5.0	^
		loz	V _{OUT} = 0 to 5.5 V		2.7 10 3.6	_	±5.0	μА
Power-off leakage current		I _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	_	10.0	μА
Quiescent supply current			V _{IN} = V _{CC} or GND		2.7 to 3.6	_	10.0	
		Icc	V _{IN} /V _{OUT} = 3.6 to 5.5 V		2.7 to 3.6		±10.0	μΑ
Increase in I _{CC} per input		Δl _{CC}	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6		500	

AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	8.0	ns
Propagation delay time	t _{pHL}	rigule 1, rigule 2	3.3 ± 0.3	1.5	7.0	
Output enable time	t _{pZL}	Figure 1, Figure 3	2.7	_	9.5	ns
Output eriable time	t _{pZH}		3.3 ± 0.3	1.5	8.5	
Output disable time	t _{pLZ}	Figure 1, Figure 3	2.7	_	8.5	ns
Output disable time	t _{pHZ}	i igure 1, i igure 3	3.3 ± 0.3	1.5	7.5	115
Output to output skew	t _{osLH}	(Note)	2.7	_	_	ns
Output to output skew	t _{osHL}	(Note)	3.3 ± 0.3	_	1.0	115

Note: Parameter guaranteed by design.

 $(t_{\text{OSLH}} = |t_{\text{pLHm}} - t_{\text{pLHn}}|, \, t_{\text{OSHL}} = |t_{\text{pHLm}} - t_{\text{pHLn}}|)$



Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

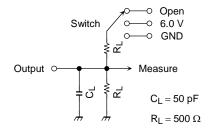
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	DIR, OE	3.3	7	pF
Bus input capacitance	C _{I/O}	An, Bn	3.3	8	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$ (Not	9) 3.3	25	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveform

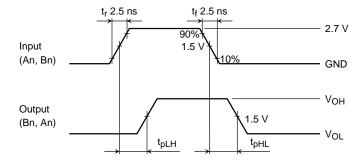
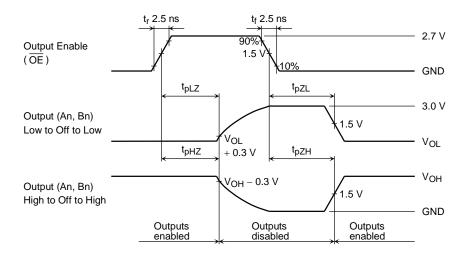


Figure 2 t_{pLH} , t_{pHL}

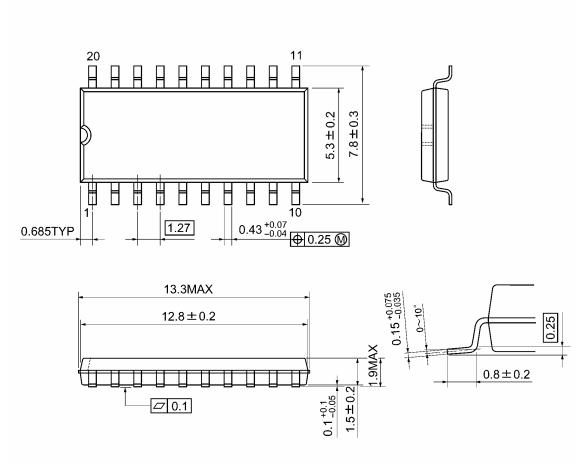


 $Figure \ 3 \quad t_{pLZ}, \, t_{pHZ}, \, t_{pZL}, \, t_{pZH}$

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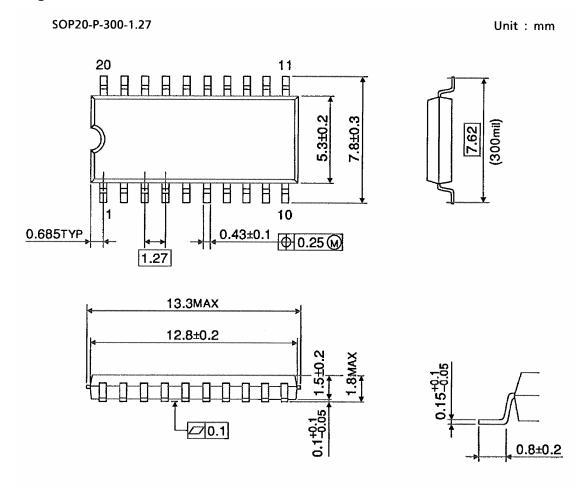
SOP20-P-300-1.27A Unit: mm



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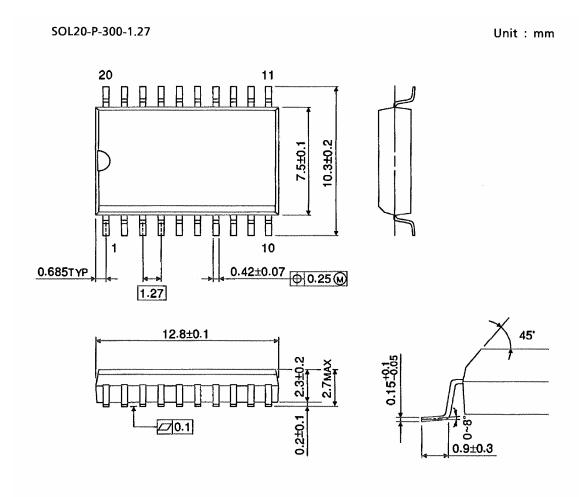
Weight: 0.22 g (typ.)





Weight: 0.22 g (typ.)

Package Dimensions (Note)



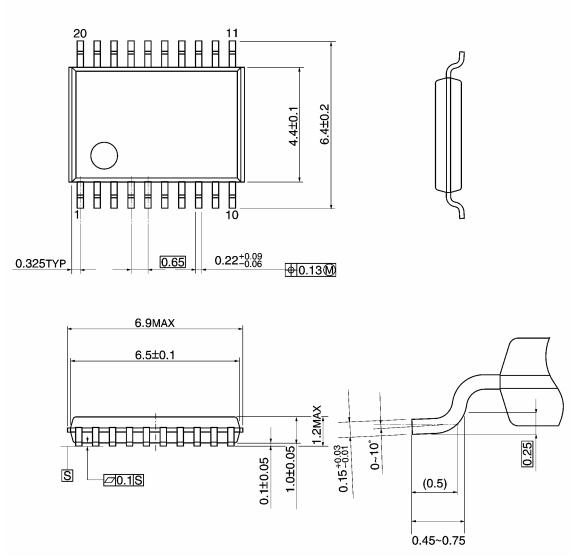
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Note This package is not available in Japan.

Weight: 0.46 g (typ.)



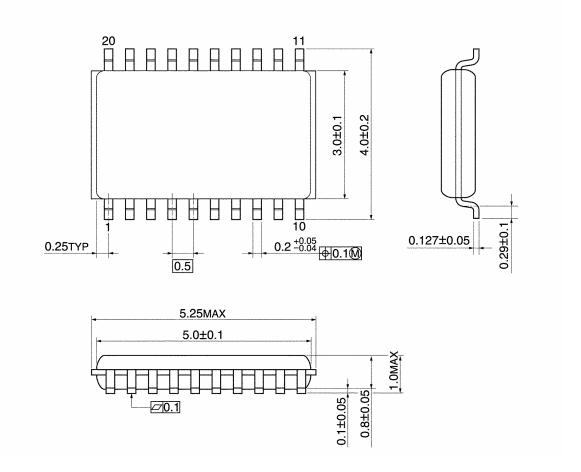
TSSOP20-P-0044-0.65A Unit: mm



Weight: 0.08 g (typ.)



VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)

Note: Lead (Pb)-Free Packages

SOP20-P-300-1.27A TSSOP20-P-0044-0.65A VSSOP20-P-0030-0.50

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